Specification.No.	Rev.Symbol	Page				Distribution No.
MOS-D-0002	v	0/10				
Spo For Miniature Pa Model HOKURIKI COMPONENTS	<u>e c i</u> int Insulat J ELECT DIVISIC	<u>fic</u> ed Fixed Ma <u>MC</u> RIC IN	2 a otal Oxi D S DUSTR	<u>t i</u> de Fil	<u>on</u> m Resist	L Nors, Flame Proof
Established Date		Revised D	ate			Applied Date
OCT. 2. 1978	1 2	. DEC.	2011		12	. DEC. 2011
To be	e kept at	ept at Appr			ved by	F. Maeda
Fnginaarin	g 500	Section -		Checked by		S. Takasalai
Lugineer I li	5 JEC			Drawn up by M. Harata		M. Haruta

FORM No. 042B

.

## REGULATION STANDARD SPECIFICATION DRAWING

REGULAT	[ION·STAN	NDARD · SPECIFICATION · DRAWING No.	No. 1				
	М	DS - D - 0002	Miniature Paint Insulated Fixed Metal Oxide Film Resistors Flame Proof				
DATE	Rev. No.	CONTENT	REASON	ISSUED	CHECKED		
1998. 09. 04	A	check whole page Change Spec.No. on ISO REGULATION MOS-D-0002	check whole page	T.Matsu- kawa	T. Naka- yama		
1999. 09. 24	В	SHEET No. 2/10 5. Dimensions and Constructions 1) Dimensions MOS1 body length:L 9. $5\pm 1.0 \rightarrow 9.0\pm 1.0$ MOS3 body length:L 16. $0\pm 1.5 \rightarrow 15.0\pm 1.5$ MOS3 body dia:D 6. $0\pm 1.0 \rightarrow 5.5\pm 1.0$	check Dimensions	H.Taka- saki	H.Waka- bayashi		
2000. 09. 07	C	SHEET No. 9/10 9. Packaging 3) taping box dimension Alter a R Ybox dimension <u>MOS1/2, 1, 2</u> (mm) <u>H</u> 155±5 W 50±5 L 340±5 ↓ <u>MOS1/2, 1</u> MOS2 (mm)	Check Dimension MOS2W RYtaping box	S.Taka- saki	H.Waka- bayashi		
		$ \begin{array}{c c c c c c c c c c c c c c c c c c c $					
2001. 01. 25	D	SHEET No. 10/10 An addition to item, "1 O.Producing district and factory name"	Expansion of Producing district	0 5 1	11 117 1		
2002. 03. 05		I U. Notes → I I. Notes SHEET No. 4/10 6. Characteristics and Test method No.11 Dielectric withstanding voltage test voltage 350V ↓ 1/2W : 250V 1~3W : 350V	訂正	5. laka- saki	H. waka- bayashi		
2002. 08. 06	E	SHEET No. 4/10 6. Characteristics and Test method No.7 solderability Characteristics 90% min. → 95% min. SHEET No. 10/10 10. Producing district and factory name (Domestic factory) PASSIVE COMPONENTS DIVISION COMPONENTS DIVISION	見直しにより 組織変更により	S. Taka- saki	S-Araki		
2003. 02. 5	F	SHEET No. 10/10 HOKURIKU (DONGGUAN) Co., Ltd. & HOKURIKU ELECTRIC INDUSTRY CO., LT D. FILM RESISTORS FACTORY FURUKAWA MANUFACTURING SECTION HOKURIKU (DONGGUAN) Co., Ltd. & OEM in Domestic factory	生産拠点の見直し	waka- bayashi	T.Naka- yama		

FORM No. 043A

### □ REGULATION □ STANDARD □ SPECIFICATION □ DRAWING

REGULA	TION·STAL	NDARD · SPECIFICATION · DRAWING No.	No. 2				
	M	O S – D – O O O 2	Miniature Paint Insulated Fixed Film Res	l Metal Ox sistors.F1	ide ame Proof		
DATE	Rev. No.	CONTENT	REASON	ISSUED	CHECKED		
2003. 02. 17	G	SHEET No. 1/10 3. table 1. Ratings Operating temperature range $-25 \sim +150^{\circ}\text{C} \rightarrow -55 \sim +200^{\circ}\text{C}$ Fig 1. Derating curve Ambient temperature/ $^{\circ}$ $-25 \sim +150^{\circ}\text{C} \rightarrow -55 \sim +200^{\circ}\text{C}$ CUEPT No. 4/10	使用温度範囲の見直し				
		SHEEL No. 4/10 table 4. Characteristics No.2. Temperature coefficient of resistance Measured by changing resistance valueat at +25°C to +125°C		waka- bayashi	T.Naka- yama		
		地記 SHEET No.10/10 HOKURIKU(DONGGUAN)Co.,Ltd. & OEM in Domestic factory	生産拠点の見直し				
2003. 09. 17	H	HOKUKIKU (DONGUOAN) Co., Lta. SHEET No.3/10 5. 寸法及び構造 2)構造 ①リード線 材料 (Sn:Pb=95:5)→(Sn-2Cu) SHEET No.4/10 表3.特性表	鉛フリー化による リード線メッキの変更	若林	中山		
		No.7 はんだ付け性 試験温度 225±5℃ 、 045±5℃					
2004. 02. 18	J	SHEET No.1/10 3. 定格 図1. 負荷軽減曲線 の変更 SHEET No.9/10 9. 包装 1)包装数量 2005/袋 $\rightarrow$ 1005/袋 2) ラベル 記載事項 type, resistance value, quantity, Lot No. maker trade mark	負荷軽減曲線図の見直し 単位数量の見直し ラベル発行システムの切替による	春田	若林		
2005. 02. 22	K	↓ type designation,quantity,manufac <u>turing No. maker trade mark</u> SHEET No.1/10 3. 定格 図1. 負荷軽減曲線 の変更	負荷軽減曲線図の見直し	春田	若林		
2005. 04. 20	L	(1/2W,1W) SHEET No.10/10 11.注意事項	RoHS指令対応による変更	春田	若林		
2005, 05, 06	M	<u>     37 KOLSTEPTCOVIC 担記</u> SHEET №8/10 4) RY型ラジアルテーピング MOS1, 2, 3 F2寸法公差 7.5±0.8 →7.5+0.6 2	RY加工寸法公差の見直し	春田	若林		
2005. 09. 14 2006. 02. 02	N //	SHEET №4/10 試験方法適用規格の変更 JIS C 5202 → JIS C 5201-1 表 3.特性表	JIS規格の改廃による変更 表記の訂正と追記	<i>*</i> <b>P</b>	╍╁┍╸┶╌		
2006. 04. 11	. 11	$100.5.1017(12.02.67.40.87) ⑦高温高湿(定常状態)「磁電於90\beta0N30\beta0FFJ→ 追記No.5.耐久性(定格負荷)「磁電於90\beta0N30\beta0FFJ→ 追記No.10.断続過負荷「抵抗値100\Omega以上に適用」追記$		<b>香</b> 田	石仲		

FORM No. 043A

### □REGULATION □STANDARD □SPECIFICATION □DRAWING

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PECIII ATTON, STANDA	DD. CDECIEICATION, DEAWING No.	No. 3				
REGULATION STANDA	IND SPECIFICATION DRAWING NO.					
MOS	$S - D - 0 \ 0 \ 0 \ 2$	Miniature Paint Insulated Fixed Film Res	Metal Ox istors.Fla	ide ame Proof		
DATE Rev. No.	CONTENT	REASON	ISSUED	CHECKED		
2006. 04. 12 P \$	<del>油店1 %8/10</del> <del>、 寸法及び構造</del> <del>)製品寸法</del> 一 <del>図2:製品外形図</del> - <del>L・(サー*線を含む全長)追加</del> - <del>」に「線長く」 - 本表表信 -</del>	(取消理由:事業本部の計画変更 による 2007.2.15)				
	<del>「小秋長さ1の変更</del> <del>MOS2(mm):38上3 → 25 (参考値)</del> <del>MOS3(mm):38上3 → 24 (参考値)</del> <del>リード線を含む全長L'寸法明記</del> <del>MOS1/2~MOS3(mm):61上3</del>		春田	若林		
3	HEEI No.8/10 ) RP型ラジアルテーピング MOS2 (mm) 日寸法 38max. → 35.5max F3寸法 6.35±1.0 → 5.85±1.0	寸法の見直し				
2006. 06. 30 Q SI	HEET №10/10 1.注意事項 4)抵抗器のはんだ付けについて 「はんだゴテによる作業の場合は ・・・・」→追記 9)お願い事項追記	表記文の見直しによる追加	春田	若林		
2006. 12. 26 R SJ 5. 1) SI 7.	HEET No.2/10 . 寸法及び構造 )製品寸法 MOS1J-ト*線径 $0.8\pm0.1 \rightarrow 0.65\pm0.1$ 加工記号・注釈文の追記 HEET No.6/10 . フォーミング加工 MOS1 R加工追記	1Wリード線径の変更	春田	若林		
SI 8. 9. 1) 7 7 3) 7 7 7 7 7 7	HEET No.7/10, 8/10 . テーピング加工 各加工に $\phi$ d寸法の追記 HEET No.9/10 . 包装 )包装数量 Nu-Nに記号附記、自立フォーミングR追記 `Uの1W記号変更→TU65, TU65H )テーピング箱寸法 `Uの1W→TU65 `U65Hの箱寸法・注釈文追記					
2007. 07. 04 S SI 5. 1)	HEET №2/10 寸法及び構造 )製品寸法のリート <sup>*</sup> 線仕様表記	リード線径表記の変更	春田	若林		
7. 7. 3)	製品形状寸法 ~ 明記 $7 + \cdot > 7$ 、製品形状寸法 1 > 1 > 1 > 1 > - 7、製品形状寸法 1 > 1 > 1 > 1 > - 1 > 1 = 1 = 1 = 1 = 1 = 1 = 1 = 1 = 1 =	寸法の見直し				
2008. 01. 15 T SH 8.	IEETNo.7/10 テーピング加工 P寸法公差:±0.3 に統一 S寸法:0.8以下 に統一 ・累積ビッチの許容差: ±1.6mm/20ピッチ→±2.0mm/20ピッチ	TP・TUテーピング図の統一及び 寸法値の規格統一	春田	高崎		
2011. 4. 26 U SH 8.	EETN₀8/10 テーピング加工 3)パナサートラジアルテーピング(RP) MOS1/2W粘着テープ幅(W)変更 12.5min. →5.5min.	・1/2WR Pテーピング 粘着テープ幅変更				

FORM No. 043A

# □REGULATION □STANDARD □SPECIFICATION □DRAWING

REGULA	TION·STAN	DARD · SPECIFICATION · DRAWING No.		TITLE		NO. 4
	МС	DS - D - 0 0 0 2	Miniature	Paint Insulated Fixed Film Res	Metal Ox: istors.Fla	ide ame Proof
DATE	Rev. No.	CONTENT	VI VI A SUC	REASON	ISSUED	CHECKED
2011, 12, 12	V	SHEET No. 10/10 HOKURIKU (DONGGUAN) Co., Ltd.	独資企業∽	への転換による社名変更	SA	(E)
	2	HOKURIKU ELECTRIC (GUANG DONG) CO.,LTD.	28	21	AND	。
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2 2	2					
3						

FORM No. 043A

SHEET No. 1 / 1 0

	Products Spec	ification;	MOS No.MC	S - D - 0	002V
Items	Contents				
1. Application	This specification covers Miniature Paint Insulated Fixed Metal Oxide Film Resistors; MOS.				
2.Model № designation	A model No. is designated as follows. ex.				
	$\frac{MOS}{MOS} = \frac{1}{1} \frac{W}{MOS} = \frac{102}{102}$	<u>    J                                </u>	<u>TU65</u>		
	Model Kated Kesistance l	olerance	Forming,		
3 Ratings	i wattage		Taping		
1)Ratings	Ratings are shown at table 1.Ratings.				
	tab	le 1.Ratin	igs		
	Items		Co	ntents	
	type	MOS1/2	MOS1	MOS2	MOS3
	Kated wattage	0.5 W		2 W	3 ₩
	Max. operational voltage	250 V	350 V	350 V	350 V
	Max. overload voltage	400 V	600 V	600 V	600 V
	Max. intermittent overload voltage	500 V	750 V	750 V	750 V
	Pated orbient temperature	250 V	<u>300 V</u>	30U V 10	350 V
	Operating temperature range		-55 °r	to +200 °	
	Resistance tolerance	clas	<u> </u>	<u>1(+5 %) K(</u>	+10 %)
		010		010	0 1 0
	Resistance range	to	to	to	to
		10 k0	100 kQ	100 kû	100 k0
	*In case of under 0.2 0 of resistance	value.res	istance to	lerance is	only
	class J and K. *Rated wattage is the maximum continu temperature from -55 °C to 70 °C. *Max. operational voltage is the D.C. by each resistor size. If calculated voltage, this Max. operational voltag *In case of ambient temperature above with Fig 1. Derating curve.	ous power or rms A. rated volt e is rated 70 °C,pow	applicable C. maximum age is ove voltage. er rating	at ambien voltages r Max. ope shall be i	t that fixed rational n accordance
	100 See 100 100 100 -55 0 70	US1/2W	MOS2W MO MOS1W	S3W 200 (	235)
	A	mbient tempe	erature/°C		
	Fig 1	.Derating	curve		
2)Rated voltage	Rated voltage is the D.C. or rms A.C. from -55 °C to 70 °C.Rated voltage sh If Rated voltage is over Max. operati to Max. operational voltage on table1	maximum v all be det onal volta	oltage at a ermined fra ge,then ra	ambient te om followi ted voltag	mperature ng formula. e is equal
	Rated voltage[V] = $\sqrt{rated watta}$	ge[W]×nom	inal resis	tance[ <b>1</b> ]	

SHEET № 2 / 1 0



SHEET № 3 / 1 0



SHEET 4 / 1 0

			Products Specification	m;MOS MOS - D - 0 0 0 2 V			
Items		Contents					
6.Character- istics	Chara	cteristics and	ole 4.Characteristics. Tistics				
and Test method		ltems	Characteristics	Test method			
	1	Resistance value	class G(± 2 %), J(± 5 %).K(±10 %)	JIS-C-5201-1 4.5			
	2	Temperature	±300 ppm/	A resistance temperature coeff			
		coefficient		icient is computed from the di			
		of		fference of resistance (R2) wi			
		resistance		th t1+100 (t2) on the basi			
				rmal temperature (t1).			
				T.C.R.= $((R2-R1)/R1)/(t2-t1) \times 10^6 \text{ ppm} /$			
	3	Short-time	resistance change	JIS-C-5201-1 4.13			
	4	Damp heat	resistance change	IIS-C-5201-1 4 24			
		(steady	within $\pm (5.0 \%+0.05)$	1) test temp.40 $\pm 2$			
		state)		2)relative humidity			
				90 % to 95 %			
				3)duration 1 000 h <sup>±</sup> 8 <sup>8</sup> h			
				Rated wattage:			
	5	Endurance	resistance change	90 mm 0N,30 mm 0FF			
		(rated load)	within $\pm (5.0 \%+0.05)$	1) test temp 70 $\pm 2$			
		,		2)duration 1 000 https://duration			
				Rated wattage:			
		Desistence	nooiotenoo ehenno	90 min ON,30 min OFF			
	0	to soldering	within $+(1.0\%+0.05)$	temp of solder and duration			
		heat		of immersion			
				260 ± 5 ,10 s ± 1 s or			
				$350 \pm 10$ , $3.5 \text{ s} \pm 0.5 \text{ s}$			
		solder-	95 %min. coverage	JIS-0-5201-1 4.17			
		ability		2) duration of immersion			
				5.0 s±0.5 s			
				3)preparation not applied			
	8	Change of	resistance change	JIS-C-5201-1 4.19			
		temperature	within ±(1.0 %+0.05 )	-25 + 3 (30 min) to normal			
				temperature(2 to 3 min)			
				+85 $\pm 3$ (30 min) to normal			
				temperature(2 to 3 min)			
		Pagiatanaa	ragiatanag abanga	2) number of cycles 5 cycles			
	9	to vibration	within $+(1.0\%+0.05)$	2)XY73-direction each 2 h			
				(6 h in total)			
	10	Intermittent	resistance change	JIS-C-5201-1 4.39			
		overload	within ± (5.0 %+0.05 )	1)applicable more than 100			
	11	Dielectric	Flash over.burning.	1)V-Block			
		withstanding	insulation damages	2)test voltage 1/2 W:250 V			
		voltage		1~3 W:350 V			
			should not be observed.	3)duration time 60 s <sup>+</sup> 1 <sup>0</sup> s			
				4) voltage increasing rate 100 V/s			
		11	1	100 1/0			

SHEET №.5/10

		-	Products Specificat	tion; MOS No.MOS - D - 0002V		
Items	Contents					
	table 3 Characteristics(continued)					
8	No.	Items	Characteristics	Test method		
	12	Terminal	lead wire break and	JIS-C-5201-1 4.16		
1		strength	terminal loose should	1)tensile force 10 N		
		(tensile	not be observed.	2)maintained time 10 s $\pm 1$ s		
		strength)				
L L		strength		1) torsional angle 360 °		
		(torsional		2) torsional times 5times		
		strength)		(0 °→360 °→0 °counted as twice)		
1		Terminal				
		strength		1) bending force 5 N		
		(bending		2) bending time $(0^{\circ} \rightarrow 0^{\circ})^{\circ} \rightarrow 0^{\circ}$		
	13	Insulation	10 GQmin	$\frac{1}{100} \frac{1}{100} \frac{1}$		
	10	resistance	io ozamin.	1)V-Block		
				2)test voltage 100 V		
				3)measured at applied		
				voltage maintained for 1 min.		
	14	Flame	flame 5 s max.in total	anlamifia malwa afi 20 hT/-3		
		(Flame		calorific value of 38 KJ/m <sup>2</sup>		
1		resistance		15 s counted loycle. This		
1		test)		cycle is carried out 5 times.		
				outer flame 127 mm		
				inner flame 38 mm		
1				an angle 45		
		Flame				
		retardance		applying A.C. voltages		
		burning		,8 times, 16 times and 32 times		
		resistance)		rated wattage each for 1 min.		
				until disconnection.		
				(regard disconnection as		
				100 times or more the nominal		
				Don't exceed either one of		
	:			4 times max. operational		
				voltage or 3 000 V.		
	15	Resistance	no remarkable	JIS-C-5201-1 4.29		
		to solvent	outward changes	1)kind of solvent		
				lsopropyl alcohol		
				(2) temp. 20 C to 25 C 3) duration 60 s $\pm 10$ s		
Ļ	1					
1   						
		<u> </u>				

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SHEET No. 6  $\swarrow 1$  0



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#### SHEET No. 7 / 1 0



SHEET №.8 / 1 0



FORM No.044A

SHEET No.9 / 1 0

		Producto	Speaif	fightion MO	S N-MOS		
Itoma			Specif		100.101 0	S-D-00	J02V
<u> </u>	Contents						
9. Packaging		sym -bol	pack -agin	MOS1/2 W	quant WOSI W	1ty   MOS2 W ]	MOSSW
i) qualities	Straight Bulk	-	bag	100pcs		100pcs	100pcs
		B65	bag		100pcs		
		L	bag	100pcs	100pcs		
	Stand-off forming	R	bag		100pcs		
	Avial papagent taning	LS TP	bag	2 000pag		100pcs	100pcs
	AXIAI panasert taping	TU	box	2 000pcs		2 000pcs	1 000pcs
	Axial universal taping	TU65	box		2 000pcs		<u> </u>
		TU65H	box		2 000pcs		
	Radial panasert taping	RP	box	2 000pcs	2 000pcs	2 000pcs	
	RYtype-Radial panasert taping	RY	box	2 000pcs	1 000pcs	500pcs	500pcs
. 1							
2)label				the item	s mentione	d	
1	Straight Bulk Model	l No. desi	ignatic	on, quantity	,lot ID nu	mber, make	r trade marl
1	Stand-off forming Model	l No. desi	gnatio	n, quantity	,lot ID nu	mber, make	r trade mark
1		L INO. desi	lgnat10	n, quantity	, lot lD nu	mber, make	r trade mark
	V	L	н ́			L	H
 	Taping box(TP·TU)		۰.		Taping	box (RP•RY)	) (mm)
	symbol	Model		Н	W		
1 1 1	Axial panasert(TP)	MOS1/2		50±5	$50 \pm 5$	5 25	$2\pm5$
	Axial TU	MOS1/2		$50\pm 5$	80±5	$\frac{5}{25}$	$\frac{2\pm 5}{2\pm 5}$
	univer TUbbH	MOS1	+ <sup>1</sup>	$10\pm 5$ $80\pm 5$	<u>80±5</u>	$\frac{5}{5}$ $\frac{25}{35}$	$\frac{2\pm 5}{0\pm 5}$
1	(TII) TII	MOS1 MOS2. 3		$\frac{80\pm5}{0.0\pm5}$	80+5	5 36	$\frac{0+5}{0+5}$
1		MOS1/2	1	$30\pm 5$	$45\pm 8$	5 32	$5\pm 5$
1 1 1	R P	MOS1	1	$7.0\pm5$	$55\pm 5$	5 32	$5\pm5$
		MOS2	2	$2.0\pm5$	55±8	5 32	$5 \pm 5$
		MOS1/2,	1 1	$55\pm5$	$50 \pm 5$	5 34	$0\pm 5$
1	RY	MOS2		$00\pm 5$	$50\pm 5$	5 34	$0\pm 5$
1 4 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	※ MOS1 TU type has two	box siz	1 e. "TU6	70 <u>+</u> 5 5H″is shor	t type, "TU	65″is long	$0 \pm 5$ type.
10 Producing	· · · · · · · · · · · · · · · · · · ·		roduci	ng distric	t and fact	ory name	7
district and	Overseas factory IIA	0-SHE ZO	NE. DON	G-KENG TOW	N.	ory name	
factory name		IOKIIBIKII	FI RCTD	DONG-GUAN,	GUANG DONG	, CHINA	
l l t	<u>تر</u> ا	UNUNINU	SLEUIK		DUNG) (U.,	LID.	

FORM No.044A

	Products Specification;MOS MOS-D-0002V						
Items	Contents						
11.Notes	<ol> <li>Storing condition         It is desirable that the Resistor are stored the room temperature at 0 to 30 and relative humidity under 65 %, are not at high-temperature, high- humidity, dusty, harmful gas, for example hydrogen chloride and sulfate gas etc.     Please not store for a long time, and mount within a year after delivered.     </li> </ol>						
	2 ) Power derating Even if have use it in a derating curve, in consideration of self-fever, ambient temperature of a resistor, heat influence from the other parts. We ask for enough load deratings in case of use in a stable state for a long term.						
	3)Resistor placing In case of the Resistor are placed around another electric parts,the distance is 5mm at least.						
	4 ) Soldering In soldering, soldering heat effect to the Resistor is as little as possible, the advised condition are under 265 and within 11 s. In case of work by soldering iron, please work in iron temperature less than 360 , less than 4 s.						
	5 ) Shock to the Resistor When the Resistor are shocked, there is danger that the Resistor breaks. So in use of insertion machine,please adjust it for no damaging to the Resistor.Please avoid dropping in a high,too.						
	6 ) Forming In forming,don't force heavily on Resistor body and welding point. Bending forms are not forced curve.						
	7 )For environmental protection We don't use Class ODC and PBBOs,PBBs in a products and the process.						
	8 )RoHS directive This resistor is a product satisfying a RoHS.						
	<ul> <li>9 ) Cautions for Resistors</li> <li>This specification shows the quality and performance as a resistor simple. Before adoption, please evaluate and check your product in which the resistor was mounted.</li> <li>This products are designed and manufactured for general standard use in</li> </ul>						
	general electronic equipment (AV equipment, household electric appliances, office equipment, information and communication equipment, etc.). When there is a danger that a human life and other serious damage will occur by the fault of this products at transportation equipment (such as train, automobile, vessel, etc.), traffic signal, medical equipment, aerospace equipment, electric heating appliances, burning appliances, gas apparatus, rotation equipment, disaster prevention, and crime prevention equipment, please design fail-safe systems and ensure safety, such as the following.						
	*Systems with protective circuits and a protective equipment *Systems with redundant circuits and others to do not cause danger by a single failure						